

YJ Planar Schottky Barrier Diode Die Specification

60V 20A, 108mil, Schottky barrier diode die based on silicon planar process

Part No.: PSB108M060AS-280A

Main Products Characteristics

~ A ϕ ^{\alpha}^{\wedge} \{ \}, \alpha \hat{a} \& \{ \wedge \} c IF(A\chi) = 20 A

~ M α \{ []^{\wedge} \alpha \} * \beta \} & dF \hat{a} \{

~ A \alpha \}) \hat{a}: